

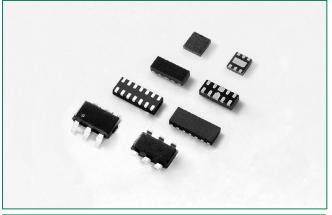
SP3012 Series 0.5pF Diode Array for USB3.0











Pinout

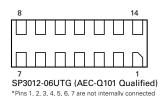


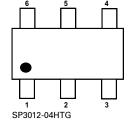
*Pins 6, 7, 9, 10 are not internally connected but should be connected to the trace.

6 7 8 9 10

5 4 3 2 1

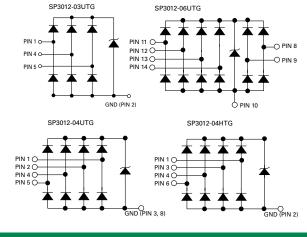
SP3012-04UTG (AEC-Q101 Qualified)





Functional Block Diagram

but should be connected to the opposite pin



Additional Information







Samples

Description

The SP3012 Series integrates either 3, 4 or 6 channels of ultra low capacitance rail-to-rail diodes and an additional zener diode to provide protection for electronic equipment that may experience destructive electrostatic discharges (ESD). These robust devices can safely absorb repetitive ESD strikes above the maximum level specified in the IEC 61000-4-2 international standard (±8kV contact discharge) without performance degradation.

The extremely low loading capacitance also makes it ideal for protecting high speed signal lines such as USB3.0, HDMI, USB2.0, and eSATA.

Features

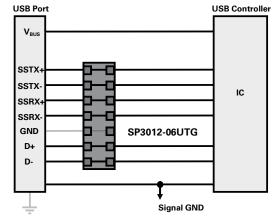
- ESD, IEC 61000-4-2, ±12kV contact, ±25kV air
- EFT, IEC 61000-4-4, 40A (t_p=5/50ns)
- Lightning, IEC 61000-4-5 2nd edition, 4A (t_P=8/20µs)
- Low capacitance of 0.5pF (TYP) per I/O
- Low leakage current of 1.5µA (MAX) at 5V
- Small form factor µDFN (JEDEC MO-229) and SOT23-6 (JEDEC MO-178AB) packages provide flow through routing to simplify PCB layout
- AEC-Q101 Qaulified (μDFN10 and μDFN14)
- RoHS compliant and leadfree

Applications

- LCD/PDPTVs
- External Storages
- DVD/Blu-ray Players
- Desktops
- MP3/PMP

- Set Top Boxes
- Smartphones
- Ultrabooks/Notebooks
- Digital Cameras
- Automotive Electronics

Application Example for USB3.0



Life Support Note:

Not Intended for Use in Life Support or Life Saving Applications

The products shown herein are not designed for use in life sustaining or life saving applications unless otherwise expressly indicated.

Absolute Maximum Ratings

Symbol	Parameter	Value	Units
I _{PP}	Peak Current (t _p =8/20µs)	4.0	А
T _{OP}	Operating Temperature	-40 to 125	°C
T _{STOR}	Storage Temperature	-55 to 150	°C

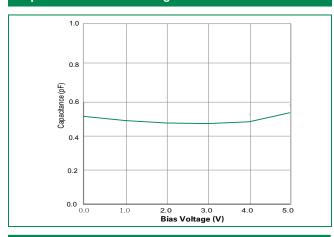
CAUTION: Stresses above those listed in "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress only rating and operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied.

Electrical Characteristics (T_{OP}=25°C)

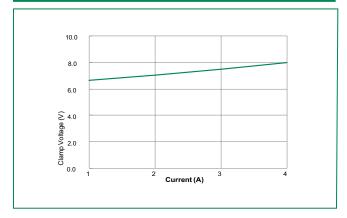
Parameter	Symbol	Test Conditions	Min	Тур	Max	Units
Reverse Standoff Voltage	V _{RWM}	$I_R \le 1 \mu A$			5.0	V
Reverse Leakage Current	I _{LEAK}	V _R =5V, Any I/O to GND			1.5	μΑ
Clamp Voltage ¹	V _C	I _{PP} =1A, t _p =8/20μs, Fwd		6.6	7.9	V
Clamp voitage	v _C	I _{pp} =2A, t _p =8/20μs, Fwd		7.0	8.4	V
Dynamic Resistance	R _{DYN}	(V _{C2} - V _{C1}) / (I _{PP2} - I _{PP1})		0.4		Ω
ESD Withstand Voltage ¹	V	IEC61000-4-2 (Contact)	±12			kV
L3D Willistalia Voltage	V _{ESD}	IEC61000-4-2 (Air)	±25			kV
Diode Capacitance ¹	C _{I/O-GND}	Reverse Bias=0V, f=1 MHz		0.5	0.65	pF
Diode Capacitance ¹	C _{I/O-/O}	Reverse Bias=0V, f=1 MHz		0.3	0.4	pF

Note: ¹ Parameter is guaranteed by design and/or device characterization.

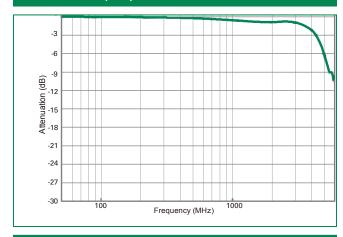
Capacitance vs. Bias Voltage



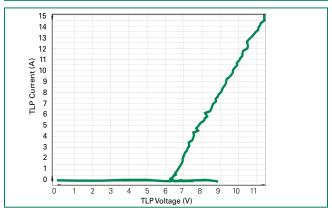
Clamping Voltage vs. I_{PP}



Insertion Loss (S21) I/O to GND



Transmission Line Pulsing(TLP) Plot





Pulse Waveform 110% 100% 90% 80% 70% 40% 50% 10% 20% 10% 0,0 5.0 10.0 15.0 20.0 25.0 30.0 Time (µs)

Product Characteristics

Lead Plating	Pre-Plated Frame (µDFN) Matte Tin (SOT23)
Lead Material	Copper Alloy
Lead Coplanarity	0.0004 inches (0.102mm)
Substitute Material	Silicon
Body Material	Molded Epoxy
Flammability	UL 94 V-0

Notes

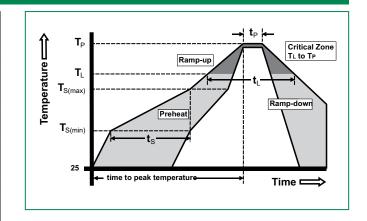
- 1. All dimensions are in millimeters
- 2. Dimensions include solder plating.
- 3. Dimensions are exclusive of mold flash & metal burr.
- 4. Blo is facing up for mold and facing down for trim/form, i.e. reverse trim/form.
- 5. Package surface matte finish VDI 11-13.

Soldering Parameters

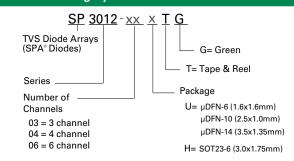
Reflow Co	ndition	Pb – Free assembly
	-Temperature Min (T _{s(min)})	150°C
Pre Heat	-Temperature Max (T _{s(max)})	200°C
	-Time (min to max) (t _s)	60 – 180 secs
Average ra	amp up rate (Liquidus) Temp k	3°C/second max
T _{S(max)} to T _I	- Ramp-up Rate	3°C/second max
Reflow	-Temperature (T _L) (Liquidus)	217°C
Reliow	-Temperature (t _L)	60 – 150 seconds
PeakTemp	erature (T _P)	260+0/-5 °C
Time within 5°C of actual peak Temperature (t _p)		20 - 40 seconds
Ramp-down Rate		6°C/second max
Time 25°C to peak Temperature (T _P)		8 minutes Max.
Do not exc	ceed	260°C

Ordering Information

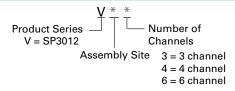
Part Number	Package	Marking	Min. Order Qty.
SP3012-03UTG	μDFN-6	V*3	3000
SP3012-04UTG	μDFN-10	V*4	3000
SP3012-06UTG	μDFN-14	V*6	3000
SP3012-04HTG	SOT23-6	V*4	3000



Part Numbering System



Part Marking System





Application Information

Signal Integrity of High-Speed Data Interfaces

Adding external ESD protection to a high-speed data port is not trivial for a variety of reasons.

- 1. ESD protection devices will add parasitic capacitance to each data line from line to GND and line to line causing impedance mismatches between the differential pairs. This ultimately affects the signal eye-diagram and whether or not the transceiver can distinguish a "1" from a "0".
- 2. ESD devices should be placed as close as possible to the port being protected to maximize their effect (i.e. clamping capability) and minimize the effect that PCB trace inductance can have during an ESD transient. Depending on the package size and pinout this could be challenging and the bigger the package, the larger the land pattern must be, which adds more parasitic capacitance.
- 3. Stub traces can add another element of discontinuity adversely affecting signal integrity so ESD protection is best employed when it's "overlaid" on the data lines or when the signals can simply pass underneath the device.

Taking all of this into account Littelfuse developed the SP3012 Series which was designed specifically for protection of high-speed data ports such as HDMI 1.3/1.4 and USB 3.0. They present less than 0.5pF from line to GND and only 0.3pF from line to line minimizing impedance mismatch between the differential pairs.

Furthermore, the SP3012 is rated up to $\pm 12kV$ (contact discharge) which far exceeds the maximum requirement of the IEC 61000-4-2 standard.

There are two options available (4 channel and 6 channel) and both are housed in leadless μ DFN packages so the data lines can pass directly underneath the device to reduce discontinuities and maintain signal integrity.

USB 3.0 Eye Diagram Data

Figure 1 shows the layout used for the SP3012-06UTG in a USB 3.0 application. The traces routed toward the top are the two legacy USB 2.0 lines (D+/D-) that run at the slower speed of 480Mbps and therefore are not as critical as the 5Gbps Super-Speed traces.

Figure 1: PCB Layout of the SP3012-06UTG for USB 3.0

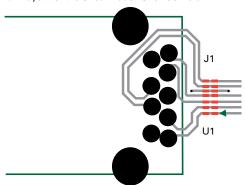


Figure 2 shows the USB 3.0 eye diagram that resulted from the PCB layout above with the SP3012-06UTG soldered on the landing pattern.

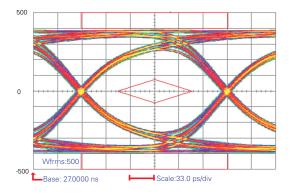


Figure 2: USB 3.0 Eye Diagram with the SP3012-06UTG

Using a similar layout as above, Figure 3 shows the eye diagram that resulted using the SP3012-04UTG to protect the Super-Speed data lines and the SP3003-02UTG to protect the legacy data pair.

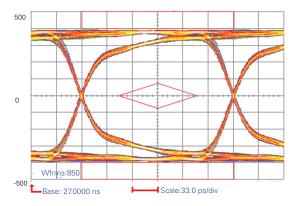
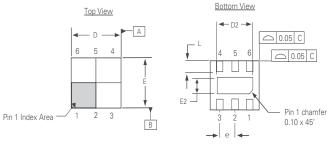
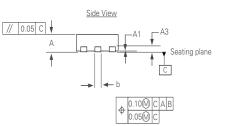


Figure 3: USB 3.0 Eye Diagram with the SP3012-04UTG



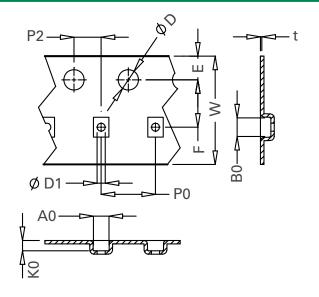
Package Dimensions — µDFN-6





Package	μDFN-6 (1.6x1.6x0.5mm)				
JEDEC		MO	-229		
	Millin	neters	Inc	hes	
Symbol	Min	Max	Min	Max	
Α	0.45	0.55	0.018	0.022	
A1	0.00	0.05	0.000	0.002	
А3	0.15	2Ref	0.006 Ref		
b	0.20	0.30	0.008	0.012	
D	1.55	1.65	0.061	0.065	
D2	1.05	1.30	0.042	0.052	
E	1.50	1.70	0.060	0.067	
E2	0.40	0.65	0.016	0.026	
е	0.50	BSC	0.020	DBSC	
L	0.164	0.316	0.006	0.012	

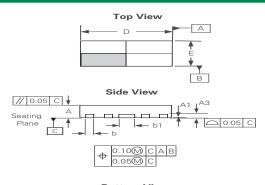
Embossed Carrier Tape & Reel Specification — µDFN-6

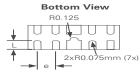


Symbol	Millin	netres	Inc	hes	
Symbol	Min	Max	Min	Max	
E	1.65	1.85	0.06	0.07	
F	3.45	3.55	0.14	0.14	
D1	1.00	1.25	0.04	0.05	
D	1.50	MIN	0.06 MIN		
P0	3.90	4.10	0.15	0.16	
10P0	40.0+	/- 0.20	1.57+/-0.01		
W	7.90	8.30	0.31	0.33	
P2	1.95	2.05	0.08	0.08	
Α0	1.78	1.88	0.07	0.07	
В0	1.78	1.88	0.07	0.07	
K0	0.84	0.94	0.03	0.04	
t	0.25	TYP	0.01	TYP	

TVS Diode Arrays (SPA® Diodes)

Package Dimensions - µDFN-10 (2.5x1.0x0.5mm)



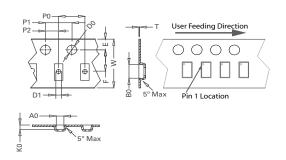


Recomended Soldering Pad Layout

Package	μDFN-10 (2.5x1.0x0.5mm)					
JEDEC			MO-2	29		
Complete		Millimeters			Inches	
Symbol	Min	Nom	Max	Min	Nom	Max
Α	0.48	0.515	0.55	0.019	0.020	0.021
A1	0.00		0.05	0.000		0.022
А3		0.125 Ref		0.005 Ref		
b	0.15	0.20	0.25	0.006	0.008	0.012
b1	0.35	0.40	0.45	0.014	0.016	0.018
D	2.40	2.50	2.60	0.094	0.098	0.102
E	0.90	1.00	1.10	0.035	0.039	0.043
е	0.50 BSC			0	.020 BSC	
L	0.30	0.365	0.43	0.012	0.014	0.016

S	Soldering Pad Layout Dimensions					
	Inch	Millimeter				
С	(0.034)	(0.875)				
G	0.008	0.20				
Р	0.020	0.50				
P1	0.039	1.00				
Х	0.008	0.20				
X1	0.016	0.40				
Υ	0.027	0.675				
Y1	(0.061)	(1.55)				
Z	0.061	1.55				

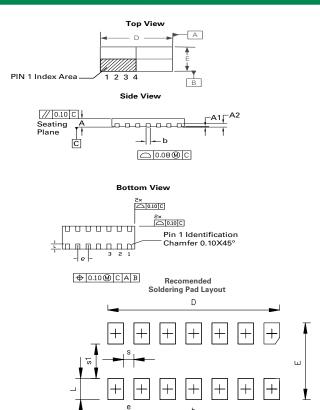
Embossed Carrier Tape & Reel Specification — µDFN-10



Package	µDFN-10 (2.5x1.0x0.5mm)
Symbol	Millimeters
A0	1.30 +/- 0.10
В0	2.83 +/- 0.10
D0	Ø 1.50 + 0.10
D1	Ø 1.00 + 0.25
E	1.75 +/- 0.10
F	3.50 +/- 0.05
K0	0.65 +/- 0.10
P0	4.00 +/- 0.10
P1	4.00 +/- 0.10
P2	2.00 +/- 0.05
Т	0.254 +/- 0.02
W	8.00 + 0.30 /- 0.10



Package Dimensions - µDFN-14 (3.5x1.35x0.5mm)



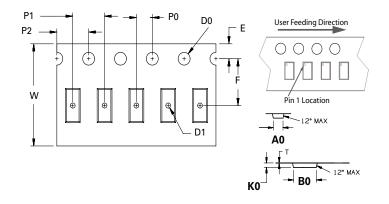
	μDFN-14 (3.5x1.35x0.5mm)						
		JEC	EC MO-22	9			
Complete		Millimeters			Inches		
Symbol	Min	Nom	Max	Min	Nom	Max	
Α	0.45	0.50	0.55	0.018	0.020	0.022	
A1	0.00	0.02	0.05	0.000	0.001	0.002	
A2		0.203 Ref		0.008 Ref			
b	0.15	0.20	0.25	0.006	0.008	0.012	
D	3.40	3.50	3.60	0.134	0.138	0.142	
D2	-	-	-	-	-	-	
E	1.25	1.35	1.45	0.050	0.054	0.058	
E1	-	-	-	-	-	-	
е	0.500 BSC			0	.020 BSC		
L	0.25	0.30	0.35	0.010	0.012	0.014	

Notes:

- 1. Dimension and tolerancing comform to ASME Y14.5M-1994.
- 2. Controlling dimensions: Millimeter. Converted Inch dimensions are not necessarily

Soldering Pad Layout Dimensions				
	Millimeters	Inches		
Symbol	Nom	Nom		
D	3.30	0.1299		
E	1.65	0.0571		
b	0.30	0.0118		
L	0.50	0.0197		
е	0.50 typ	0.020 typ		
S	0.20	0.0078		
s1	0.65	0.0256		

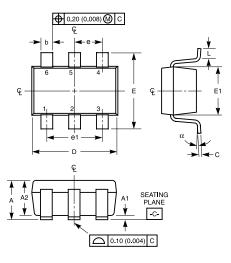
Embossed Carrier Tape & Reel Specification — µDFN-14



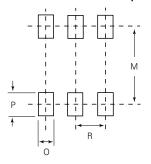
Symbol	Millimeters			
A0	1.58 +/- 0.10			
В0	3.73 +/- 0.10			
D0	Ø 1.50 + 0.10			
D1	Ø 0.60 +/- 0.05			
E	1.75 +/- 0.10			
F	5.50 +/- 0.05			
K0	0.68 + 0.12/-0.10			
P0	2.00 +/- 0.05			
P1	4.00 +/- 0.10			
P2	4.00 +/- 0.10			
T	0.28 +0.02/ -0.05			
w	12.00 + 0.30 /- 0.10			



Package Dimensions — SOT23-6



Recommended Solder Pad Layout



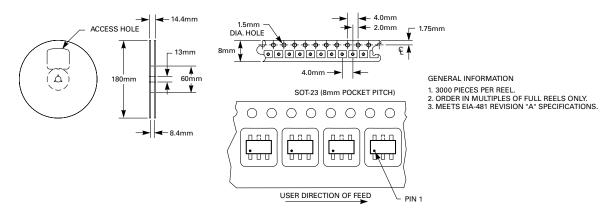
Package	SOT23					
Pins	6					
JEDEC	MO-178AB					
	Millimeters		Inches		Nistan	
	Min	Max	Min	Max	Notes	
Α	0.900	1.450	0.035	0.057	-	
A1	0.000	0.150	0.000	0.006	-	
A2	0.900	1.300	0.035	0.051	-	
b	0.350	0.500	0.0138	0.0196	-	
С	0.080	0.220	0.0031	0.009	-	
D	2.800	3.000	0.11	0.118	3	
E	2.600	3.000	0.102	0.118	-	
E1	1.500	1.750	0.06	0.069	3	
е	0.95 Ref		0.0374 ref		-	
e1	1.9 Ref		0.0748 Ref		-	
L	0.30	0.600	0.012	0.023	4,5	
N	6		6		6	
α	0°	8°	0°	8°	-	
М		2.590		0.102	-	
0		0.690		.027 TYP	-	
P		0.990		.039 TYP	-	
R		0.950		0.038	-	

Notes:

- Dimensioning and tolerancing Per ASME Y14.5M-1994.
 Package conforms to EIAJ SC-74 (1992).
 Dimensions D and E1 are exclusive of mold flash, protrusions, or gate burrs.
- Foot length L measured at reference to seating plane.
 "L" is the length of flat foot surface for soldering to substrate.
- "N" is the number of terminal positions.
- Controlling dimension: MILLIMETER. Converted inch dimensions are not necessarily exact.

Embossed Carrier Tape & Reel Specification — SOT23-6

8mm TAPE AND REEL



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